

EGP20A - EGP20K

Features

- Glass passivated cavity-free junction.
- High surge current capability.
- Low leakage current.
- Superfast recovery time for high efficiency.
- Low forward voltage, high current capability.



DO-15 COLOR BAND DENOTES CATHODE

Fast Rectifiers (Glass Passivated)

Absolute Maximum Ratings* T_A = 25°C unless otherwise noted

Symbol	Parameter		Value							
		20A	20B	20C	20D	20F	20G	20J	20K]
V_{RRM}	Maximum Repetitive Reverse Voltage		100	150	200	300	400	600	800	V
I _{F(AV)}	Average Rectified Forward Current, .375 " lead length @ $T_A = 55^{\circ}$ C 2.0			•	А					
I _{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave		75						Α	
T _{stg}	Storage Temperature Range -65 to +150			°C						
T _J	Operating Junction Temperature -65 to +150				°C					

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P _D	Power Dissipation	3.15	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	15	°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter		Device							Units
			20B	20C	20D	20F	20G	20J	20K	
V _F	Forward Voltage @ 2.0 A		0.95			1.25		1.7		V
t _{rr}	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		50					75		ns
I _R	Reverse Current @ rated V_R $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$	5.0 100			μA μA					
Ст	Total Capacitance V _R = 4.0 V, f = 1.0 MHz	70 45			pF					

Typical Characteristics

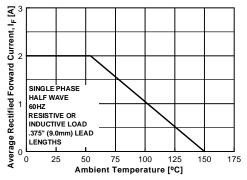


Figure 1. Forward Current Derating Curve

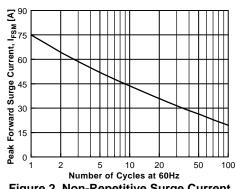


Figure 2. Non-Repetitive Surge Current

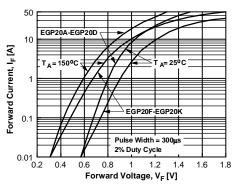


Figure 3. Forward Voltage Characteristics

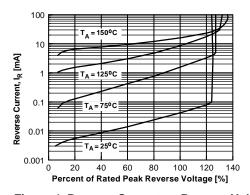


Figure 4. Reverse Current vs Reverse Voltage

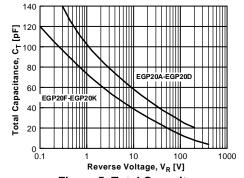
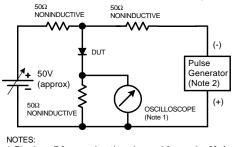
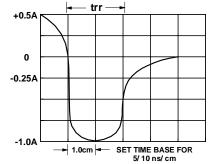


Figure 5. Total Capacitance



1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf. 2. Rise time = 10 ns max; Source impedance = 50 ohms.



Reverse Recovery Time Characterstic and Test Circuit Diagram

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